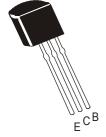




An IS/ISO 9002 and IECQ Certified Manufacturer

NPN SILICON PLANAR TRANSISTOR

CD965



TO-92 Plastic Package

Used for Medium Power Amplifier Applications

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage	V _{CEO}	20	V
Collector Base Voltage	V _{CBO}	40	V
Emitter Base Voltage	V _{EBO}	7	V
Collector Current Continuous	I _C	5	Α
Pe	ak I _{CP}	8	Α
Power Dissipation	P _C	0.75	W
Junction Temperature	T _j	150	°C
StorageTemperature Range	T _{stg}	-55 to +150	°C

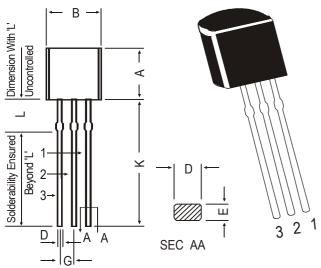
ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

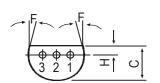
DESCRIPTION	SYMBOL	TEST CONDITION	VALUE	UNIT
Collector Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA,	>20 >40	V
Collector Base Emitter Voltage	BV _{CBO}	I _C =100μA		V
Emitter Base Breakdown Voltage	BV_{EBO}	I _E =10μA	>7	V
Collector Cut off Current	I _{CBO}	V _{CB} =10V	<100	nA
Emitter Cut off Current	I _{EBO}	V _{EB} =7V	<100	nA
DC Current Gain	h _{FE}	V _{CE} =2V,I _C =500mA	180-600	
	h _{FE}	CD965P	180-270	
	h _{FE}	CD965Q	230-380	
	h _{FE}	CD965R	340-600	
	h _{FE}	$V_{CE}=2V,I_{C}=2A$	>150	
Collector Emitter (sat) Voltage	V _{CE (sat)}	I _C =3A, I _B =100mA	<1.35	V
Base Emitter (sat) Voltage	V _{BE (sat)}	I _C =1A, I _B =25mA	<1.2	V
DYNAMIC CHARACTERISTICS				
Gain Bandwith Product	f _T	I _C =50mA, V _{CE} =6V	150(typ)	MHz
Output Capacitance	C _{ob}	f=1MHz, V _{CB} =20V	<50	pF

TO-92 Plastic Package

TO-92 Plastic Package

TO-92 Transistors on Tape and Ammo Pack



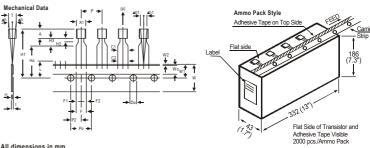


PIN CONFIGURATION

- 1. BASE
- 2. COLLECTOR
- 3. EMITTER

SEC AA							
DIM	MIN.	MAX.					
Α	4.32	5.33					
В	4.45	5.20					
С	3.18	4.19					
D	0.41	0.55					
Е	0.35	0.50					
F	5 DI	EG					
G	1.14	1.40					
Н	1.14	1.53					
K	12.70						
L	1.982	2.082					
All dissipations in the same							

All diminsions in mm.



All dimensions in mm

		SPECIFICATION			ION	
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	REMARKS
BODY WIDTH	A1	4.0		4.8		
BODY HEIGHT	Α	4.8		5.2		
BODY THICKNESS	T	3.9		4.2		
PITCH OF COMPONENT	P		12.7		± 1.0	
FEED HOLE PITCH	Po		12.7		± 0.3	CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH
FEED HOLE CENTRE TO						
COMPONENT CENTRE	P2		6.35		± 0.4	TO BE MEASURED AT BOTTOM OF CLINCH
DISTANCE BETWEEN OUTER					+ 0.6	
LEADS	F		5.08		- 0.2	
COMPONENT ALIGNMENT SIDE VIEW	∆h		0	1.0		AT TOP OF BODY
COMPONENT ALIGNMENT FRONT VIEW	∆h1		0	1.3		AT TOP OF BODY
TAPE WIDTH	W		18		± 0.5	
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	
HOLE POSITION	W1		9		+ 0.7	
					- 0.5	
HOLD-DOWN TAPE POSITION	W2		0.5		± 0.2	
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5	
COMPONENT HEIGHT	H1			23.25		
LENGTH OF SNIPPED LEADS	L			11.0		
FEED HOLE DIAMETER	Do		4		± 0.2	
TOTAL TAPE THICKNESS	t			1.2		t1 0.3-0.6
LEAD - TO - LEAD DISTANCE	F1, F2		2.54		+ 0.4	
STAND OFF	H2	0.45		1.45	- 0.1	
CLINCH HEIGHT	H3			3.0		
LEAD PARALLELISM	C1 - C2			0.22		
PULL - OUT FORCE	(P)	6N				

- NOTES

 1. Maximum alignment deviation between leads will not to be greater than 0.2mm.

 2. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.

 3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.

 4. There will be no more than three (3) consecutive missing components in a tape.

 5. A tape traiter, having at least three feed holes are provided after the last component in a tape.

 6. Splices should not interfere with the sprocket feed holes.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight /Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

Notes CD965

> TO-92 **Plastic Package**

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.

CDIL is a registered Trademark of

Continental Device India Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290

e-mail sales@cdil.com www.cdil.com